

## DS90C385/DS90C365 +3.3V Programmable LVDS Transmitter 24-Bit Flat Panel Display (FPD) Link-85 MHz, +3.3V Programmable LVDS Transmitter 18-Bit Flat Panel Display (FPD) Link-85 MHz

### **General Description**

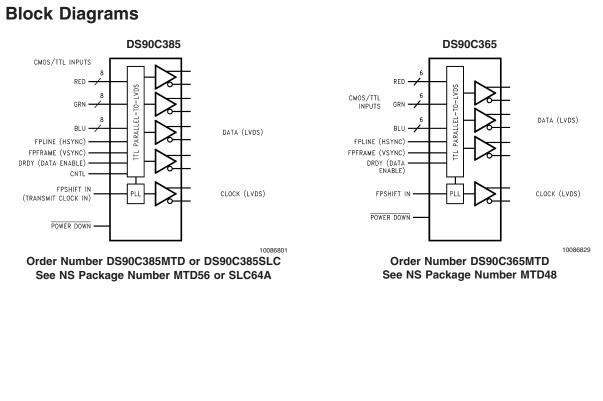
The DS90C385 transmitter converts 28 bits of LVCMOS/ LVTTL data into four LVDS (Low Voltage Differential Signaling) data streams. A phase-locked transmit clock is transmitted in parallel with the data streams over a fifth LVDS link. Every cycle of the transmit clock 28 bits of input data are sampled and transmitted. At a transmit clock frequency of 85 MHz, 24 bits of RGB data and 3 bits of LCD timing and control data (FPLINE, FPFRAME, DRDY) are transmitted at a rate of 595 Mbps per LVDS data channel. Using a 85 MHz clock, the data throughput is 297.5 Mbytes/sec. Also available is the DS90C365 that converts 21 bits of LVCMOS/ LVTTL data into three LVDS (Low Voltage Differential Signaling) data streams. Both transmitters can be programmed for Rising edge strobe or Falling edge strobe through a dedicated pin. A Rising edge or Falling edge strobe transmitter will interoperate with a Falling edge strobe Receiver (DS90CF386/DS90CF366) without any translation logic.

The DS90C385 is also offered in a 64 ball, 0.8mm fine pitch ball grid array (FBGA) package which provides a 44 % reduction in PCB footprint compared to the TSSOP package.

This chipset is an ideal means to solve EMI and cable size problems associated with wide, high-speed TTL interfaces.

#### Features

- 20 to 85 MHz shift clock support
- Best-in-Class Set & Hold Times on TxINPUTs Tx power consumption <130 mW (typ) @85MHz</p> Grayscale
- Tx Power-down mode <200µW (max)
- Supports VGA, SVGA, XGA and Dual Pixel SXGA.
- Narrow bus reduces cable size and cost
- Up to 2.38 Gbps throughput
- Up to 297.5 Megabytes/sec bandwidth
- 345 mV (typ) swing LVDS devices for low EMI
- PLL requires no external components
- Compatible with TIA/EIA-644 LVDS standard
- Low profile 56-lead or 48-lead TSSOP package
- DS90C385 also available in a 64 ball, 0.8mm fine pitch ball grid array (FBGA) package



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S90C385/DS90C365 +3.3V Programmable LVDS Transmitter 24-Bit Flat Panel Display (FPD)

## Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Supply Voltage (V <sub>CC</sub> )	-0.3V to +4V
CMOS/TTL Input Voltage	–0.5V to (V <sub>CC</sub> + 0.3V)
LVDS Driver Output Voltage	-0.3V to (V <sub>CC</sub> + 0.3V)
LVDS Output Short Circuit	
Duration	Continuous
Junction Temperature	+150°C
Storage Temperature	−65°C to +150°C
Lead Temperature	
(Soldering, 4 sec)	+260°C
Solder reflow Temperature	
(20 sec for FBGA)	+220°C
Maximum Package Power Dissip	pation Capacity @ 25°C
MTD56 (TSSOP) Package:	
DS90C385MTD	1.63 W
MTD48 (TSSOP) Package:	
DS90C365MTD	1.98 W
SLC64 (FBGA) Package:	

DS90C385SLC	2.0 W
Package Derating:	
DS90C385MTD	12.5 mW/°C above +25°C
Package Derating:	
DS90C365MTD	16 mW/°C above +25°C
DS90C385SLC	10.2 mW/°C above +25°C
ESD Rating	
(HBM, 1.5kΩ, 100pF)	> 7 kV
(EIAJ, 0Ω, 200 pF)	> 500V
Latch Up Tolerance @ 25°C	> ±300mA

## Recommended Operating Conditions

	Min	Nom	Max	Units	
Supply Voltage (V <sub>CC</sub> )	3.0	3.3	3.6	V	
Operating Free Air					
Temperature (T <sub>A</sub> )	-10	+25	+70	°C	
Supply Noise Voltage ( $V_{CC}$ )			100	mV <sub>PP</sub>	
TxCLKIN frequency	20		85	MHz	

#### **Electrical Characteristics**

Over recommended operating supply and temperature ranges unless otherwise specified.

Symbol	Parameter	Conditio	ons	Min	Тур	Max	Units
LVCMOS	/LVTTL DC SPECIFICATIONS			_1		I	
V <sub>IH</sub>	High Level Input Voltage			2.0		V <sub>cc</sub>	V
V <sub>IL</sub>	Low Level Input Voltage			GND		0.8	V
V <sub>CL</sub>	Input Clamp Voltage	I <sub>CL</sub> = -18 mA			-0.79	-1.5	V
I <sub>IN</sub>	Input Current	$V_{IN} = 0.4V, 2.5V \text{ or } V_{CC}$	;		+1.8	+10	μA
		V <sub>IN</sub> = GND		-10	0		μA
LVDS DO	C SPECIFICATIONS						
V <sub>OD</sub>	Differential Output Voltage	$R_L = 100\Omega$		250	345	450	mV
$\Delta V_{OD}$	Change in V <sub>OD</sub> between					35	mV
	complimentary output states						1
V <sub>os</sub>	Offset Voltage (Note 4)			1.125	1.25	1.375	V
۵۷ <sub>os</sub>	Change in V <sub>OS</sub> between					35	mV
	complimentary output states						1
l <sub>os</sub>	Output Short Circuit Current	$V_{OUT} = 0V, R_L = 100\Omega$			-3.5	-5	mA
oz	Output TRI-STATE® Current	Power Down = 0V,			±1	±10	μA
		$V_{OUT}$ = 0V or V <sub>CC</sub>					1
TRANSM	NITTER SUPPLY CURRENT						
ICCTW	Transmitter Supply Current	$R_L = 100\Omega$ ,	f = 32.5 MHz		31	45	mA
	Worst Case	C <sub>L</sub> = 5 pF,	f = 40 MHz		32	50	mA
	DS90C385	Worst Case Pattern	f = 65 MHz		37	55	mA
		(Figures 1, 4)	f = 85 MHz		42	60	mA
ICCTG	Transmitter Supply Current	R <sub>L</sub> = 100Ω,	f = 32.5 MHz		29	38	mA
	16 Grayscale	$C_{L} = 5 \text{ pF},$	f = 40 MHz		30	40	mA
	DS90C385	16 Grayscale Pattern	f = 65 MHz		35	45	mA
		(Figures 2, 4)	f = 85 MHz		39	50	mA

## Electrical Characteristics (Continued)

Over recommended operating supply and temperature ranges unless otherwise specified.

Symbol	Parameter	Conditio	ons	Min	Тур	Мах	Units
TRANSM	ITTER SUPPLY CURRENT	·		•			
ICCTW	Transmitter Supply Current	$R_L = 100\Omega$ ,	f = 32.5 MHz		28	42	mA
	Worst Case	C <sub>L</sub> = 5 pF,	f = 40 MHz		29	47	mA
	DS90C365	Worst Case Pattern	f = 65 MHz		34	52	mA
		(Figures 1, 4)	f = 85 MHz		39	57	mA
ICCTG	Transmitter Supply Current	R <sub>L</sub> = 100Ω,	f = 32.5 MHz		26	35	mA
	16 Grayscale	$C_L = 5 \text{ pF},$	f = 40 MHz		27	37	mA
	DS90C365	16 Grayscale Pattern	f = 65 MHz		32	42	mA
		(Figures 3, 4)	f = 85 MHz		36	47	mA
ICCTZ	Transmitter Supply Current	Power Down = Low			10	55	μA
	Power Down	Driver Outputs in TRI-S	TATE under				
		Power Down Mode					

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. They are not meant to imply that the device should be operated at these limits. The tables of "Electrical Characteristics" specify conditions for device operation.

Note 2: Typical values are given for V<sub>CC</sub> = 3.3V and T<sub>A</sub> = +25C.

Note 3: Current into device pins is defined as positive. Current out of device pins is defined as negative. Voltages are referenced to ground unless otherwise specified (except  $V_{OD}$  and  $\Delta V_{OD}$ ).

Note 4:  $V_{OS}$  previously referred as  $V_{CM}$ .

## **Recommended Transmitter Input Characteristics**

Over recommended operating supply and temperature ranges unless otherwise specified

Symbol	Parameter	Min	Тур	Max	Units
TCIT	TxCLK IN Transition Time (Figure 6)	1.0		6.0	ns
TCIP	TxCLK IN Period (Figure 7)	11.76	Т	50	ns
TCIH	TxCLK IN High Time (Figure 7)	0.35T	0.5T	0.65T	ns
TCIL	TxCLK IN Low Time (Figure 7)	0.35T	0.5T	0.65T	ns
TXIT	TxIN Transition Time	1.5		6.0	ns

## **Transmitter Switching Characteristics**

Over recommended operating supply and temperature ranges unless otherwise specified

Symbol	Parameter		Min	Тур	Max	Units
LLHT	LVDS Low-to-High Transition Time (Figure 5)			0.75	1.5	ns
LHLT	LVDS High-to-Low Transition Time (Figure 5)			0.75	1.5	ns
TPPos0	Transmitter Output Pulse Position for Bit 0 (Figures 13, 14)	f = 40 MHz	-0.25	0	0.25	ns
	(Note 5)					
TPPos1	Transmitter Output Pulse Position for Bit 1		3.32	3.57	3.82	ns
TPPos2	Transmitter Output Pulse Position for Bit 2		6.89	7.14	7.39	ns
TPPos3	Transmitter Output Pulse Position for Bit 3		10.46	10.71	10.96	ns
TPPos4	Transmitter Output Pulse Position for Bit 4		14.04	14.29	14.54	ns
TPPos5	Transmitter Output Pulse Position for Bit 5		17.61	17.86	18.11	ns
TPPos6	Transmitter Output Pulse Position for Bit 6		21.18	21.43	21.68	ns
TPPos0	Transmitter Output Pulse Position for Bit 0 (Figures 13, 14)	f = 65 MHz	-0.20	0	0.20	ns
	(Note 5)					
TPPos1	Transmitter Output Pulse Position for Bit 1		2.00	2.20	2.40	ns
TPPos2	Transmitter Output Pulse Position for Bit 2		4.20	4.40	4.60	ns
TPPos3	Transmitter Output Pulse Position for Bit 3		6.39	6.59	6.79	ns
TPPos4	Transmitter Output Pulse Position for Bit 4		8.59	8.79	8.99	ns
TPPos5	Transmitter Output Pulse Position for Bit 5	7	10.79	10.99	11.19	ns
TPPos6	Transmitter Output Pulse Position for Bit 6	7	12.99	13.19	13.39	ns

<b>Transmitter Switching</b>	Characteristics	(Continued)
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Over recommended operating supply and temperature ranges unless otherwise specified

Symbol	Parameter		Min	Тур	Max	Units
TPPos0	Transmitter Output Pulse Position for Bit 0 ( <i>Figures 13, 14</i> ) (Note 5)	f = 85 MHz	-0.20	0	0.20	ns
TPPos1	Transmitter Output Pulse Position for Bit 1		1.48	1.68	1.88	ns
TPPos2	Transmitter Output Pulse Position for Bit 2		3.16	3.36	3.56	ns
TPPos3	Transmitter Output Pulse Position for Bit 3		4.84	5.04	5.24	ns
TPPos4	Transmitter Output Pulse Position for Bit 4		6.52	6.72	6.92	ns
TPPos5	Transmitter Output Pulse Position for Bit 5		8.20	8.40	8.60	ns
TPPos6	Transmitter Output Pulse Position for Bit 6		9.88	10.08	10.28	ns
TSTC	TxIN Setup to TxCLK IN (Figure 7)	·	2.5			ns
THTC	TxIN Hold to TxCLK IN (Figure 7)		0			ns
TCCD	TxCLK IN to TxCLK OUT Delay (Figure 8)	$T_{A} = 25^{\circ}C, V_{CC} = 3.3V$	3.8		6.3	ns
	TxCLK IN to TxCLK OUT Delay (Figure 8)	•	2.8		7.1	ns
TJCC	Transmitter Jitter Cycle-to-Cycle (Figures 15, 16) (Note 6)	f = 85 MHz		110	150	ps
		f = 65 MHz		210	230	ps
		f = 40 MHz		350	370	ps
TPLLS	Transmitter Phase Lock Loop Set (Figure 9)				10	ms
TPDD	Transmitter Power Down Delay (Figure 12)				100	ns

Note 5: The Minimum and Maximum Limits are based on statistical analysis of the device performance over process, voltage, and temperature ranges. This parameter is functionality tested only on Automatic Test Equipment (ATE).

Note 6: The limits are based on bench characterization of the device's jitter response over the power supply voltage range. Output clock jitter is measured with a cycle-to-cycle jitter of +/–3ns applied to the input clock signal while data inputs are switching (See Figures 15 and 16). A jitter event of 3ns, represents worse case jump in the clock edge from most graphics controller VGA chips currently available. This parameter is used when calculating system margin as described in AN-1059.

## **AC Timing Diagrams**

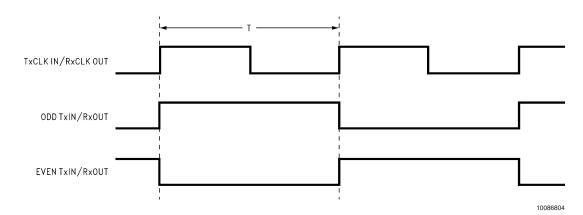


FIGURE 1. "Worst Case" Test Pattern (Note 7)

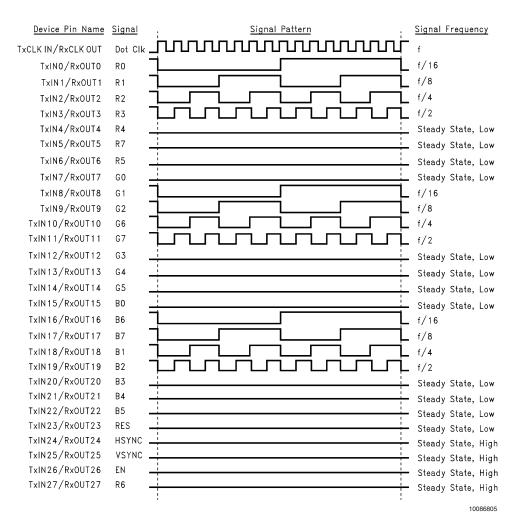
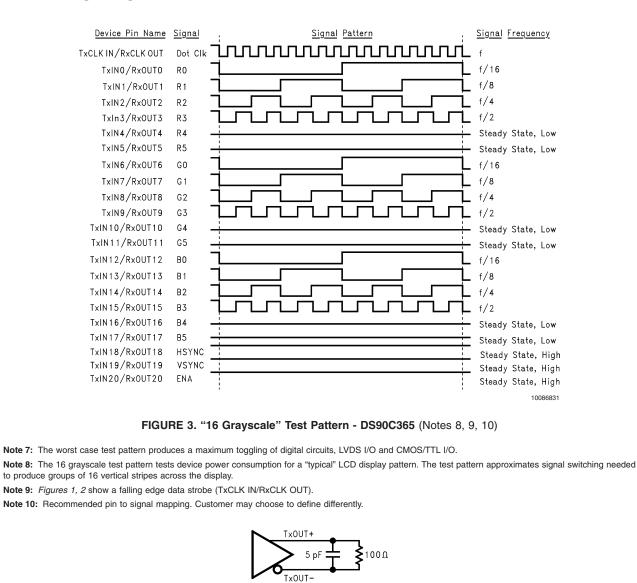
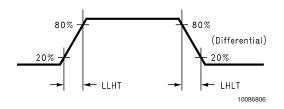


FIGURE 2. "16 Grayscale" Test Pattern - DS90C385 (Notes 8, 9, 10)



#### FIGURE 4. DS90C385/DS90C365 (Transmitter) LVDS Output Load

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#### FIGURE 5. DS90C385/DS90C365 (Transmitter) LVDS Transition Times

#### AC Timing Diagrams (Continued) - 3V 90% 90% 10% 10% TxCLK IN . Ô٧ TCIT TCIT 10086808 FIGURE 6. DS90C385/DS90C365 (Transmitter) Input Clock Transition Time Sample on H→L Edge TCIP TxCLK IN 3 V 2.0V 2.0V 2.0\ 0.81 TCIH 0٧ TCIL THTC-TSTC 3٧ TxIN 0:27 1.5 Setup Hold 1.5V 0٧ 10086810 FIGURE 7. DS90C385/DS90C365 (Transmitter) Setup/Hold and High/Low Times (Falling Edge Strobe) TxCLK IN TCCD TxCLK OUT 10086812 FIGURE 8. DS90C385/DS90C365 (Transmitter) Clock In to Clock Out Delay 3.0V POWER DOWN 3.6V 3.0V V<sub>CC</sub> TPLLS

3٧

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Vdiff

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FIGURE 9. DS90C385/DS90C365 (Transmitter) Phase Lock Loop Set Time

TxCLK IN

TxCLK OUT

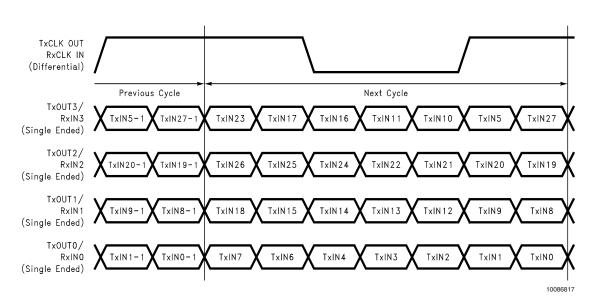


FIGURE 10. 28 Parallel TTL Data Inputs Mapped to LVDS Outputs - DS90C385

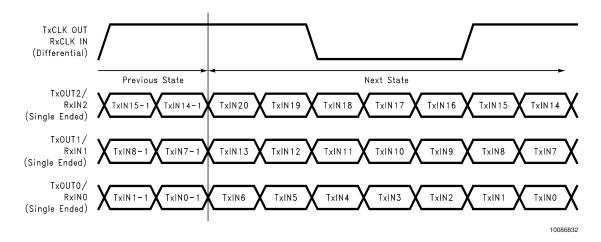


FIGURE 11. 21 Parallel TTL Data Inputs Mapped to LVDS Outputs - DS90C365

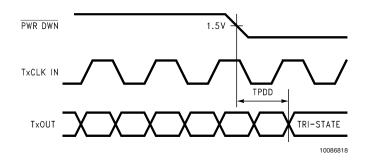


FIGURE 12. Transmitter Power Down Delay

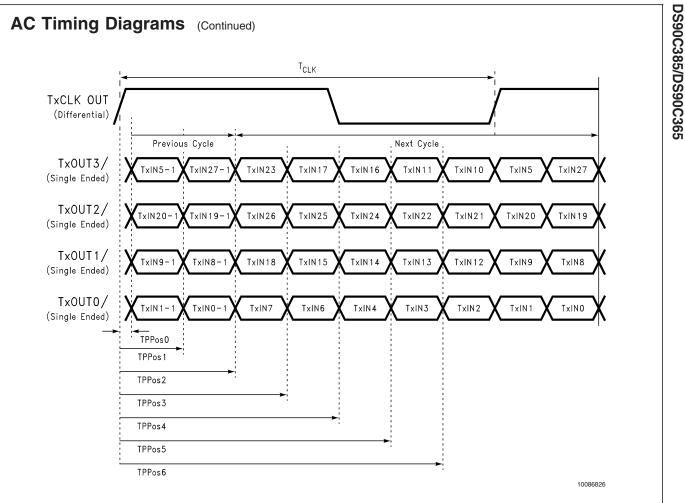


FIGURE 13. Transmitter LVDS Output Pulse Position Measurement - DS90C385

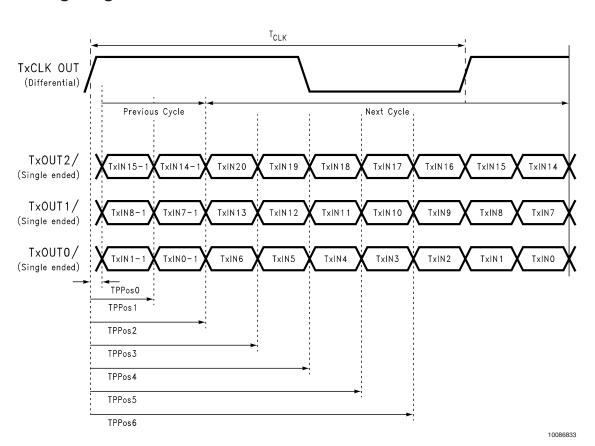


FIGURE 14. Transmitter LVDS Output Pulse Position Measurement - DS90C365

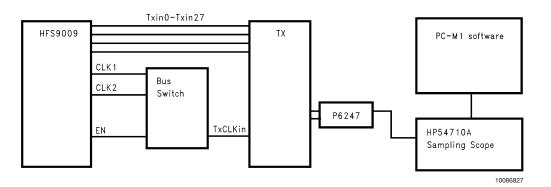
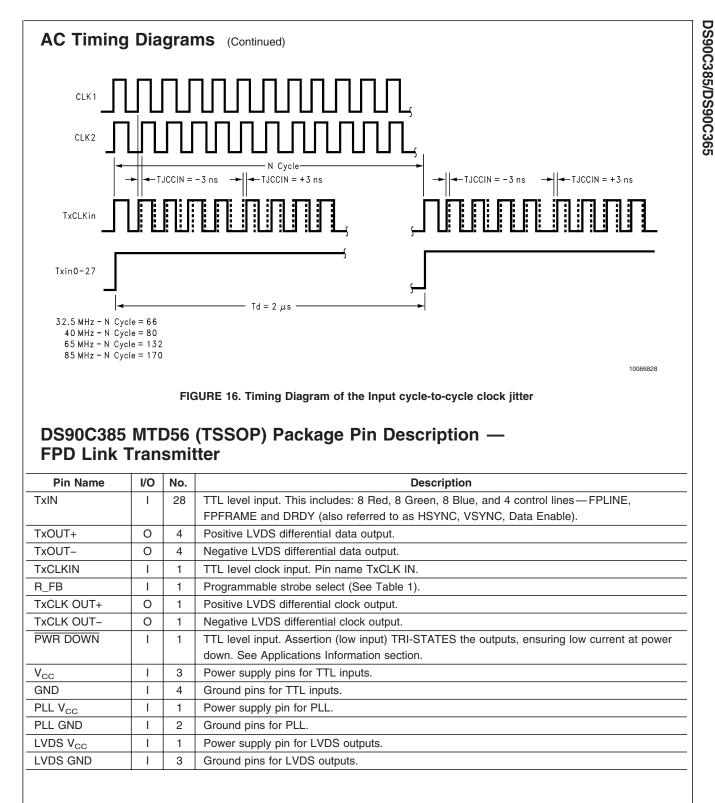


FIGURE 15. TJCC Test Setup - DS90C385 Shown



# DS90C385SLC SLC64A (FBGA) Package Pin Summary — FPD Link Transmitter

Pin Name	I/O	No.	Description
TxIN	1	28	TTL level input.
TxOUT+	0	4	Positive LVDS differential data output.
TxOUT-	0	4	Negative LVDS differential data output.
TxCLKIN	1	1	TTL level clock input. The rising edge acts as data strobe. Pin name TxCLK IN.
R_FB	1	1	Programmable strobe select. HIGH = rising edge, LOW = falling edge.
TxCLK OUT+	0	1	Positive LVDS differential clock output.
TxCLK OUT-	0	1	Negative LVDS differential clock output.
PWR DOWN	1	1	TTL level input. Assertion (low input) TRI-STATES the outputs, ensuring low current at
			power down. See Applications Information section.
V <sub>CC</sub>	I	3	Power supply pins for TTL inputs.
GND	I	5	Ground pins for TTL inputs.
PLL V <sub>CC</sub>	I	1	Power supply pin for PLL.
PLL GND	I	2	Ground pins for PLL.
LVDS V <sub>CC</sub>	I	2	Power supply pin for LVDS outputs.
LVDS GND	I	4	Ground pins for LVDS outputs.
NC		6	Pins not connected.

## DS90C385SLC SLC64A (FBGA) Package Pin Description — FPD Link Transmitter

	By Pin	
Pin	Pin Name	Туре
A1	TxIN27	1
A2	TxOUT0-	0
A3	TxOUT0+	0
A4	LVDS VCC	Р
A5	LVDS VCC	Р
A6	TxCLKOUT-	0
A7	TxCLKOUT+	0
A8	TxOUT3+	0
B1	TxIN1	I
B2	TxIN0	I
B3	LVDS GND	G
B4	LVDS GND	G
B5	TxOUT2-	0
B6	TxOUT3-	0
B7	LVDS GND	G
B8	NC	
C1	TxIN3	1
C2	NC	
C3	NC	
C4	TxOUT1-	0
C5	TxOUT2+	0
C6	PLL GND	G
C7	PLL VCC	Р
C8	TxCLKIN	I
D1	TxIN4	I
D2	TxIN2	I
D3	GND	G

	By Pin Type	
Pin	Pin Name	Туре
D3	GND	G
E4	GND	G
E8	GND	G
G1	GND	G
G6	GND	G
B3	LVDS GND	G
B4	LVDS GND	G
B7	LVDS GND	G
D5	LVDS GND	G
C6	PLL GND	G
D6	PLL GND	G
D7	PWR DOWN	I
G5	R_FB	I
C8	TxCLKIN	
B2	TxIN0	I
B1	TxIN1	
D2	TxIN2	I
C1	TxIN3	I
D1	TxIN4	I
F1	TxIN5	I
E2	TxIN6	I
E3	TxIN7	I
G2	TxIN8	I
H1	TxIN9	I
G3	TxIN10	I
H3	TxIN11	I
F4	TxIN12	I

# DS90C385SLC SLC64A (FBGA) Package Pin Description — FPD Link Transmitter (Continued)

DS90C385/DS90C365

	manomittor	(continucu)	
	By Pin		
D4	TxOUT1+	0	1
D5	LVDS GND	G	1
D6	PLL GND	G	1
D7	PWD DOWN	1	1
D8	TxIN26	1	1
E1	VCC	Р	1
E2	TxIN6	1	1
E3	TxIN7	1	1
E4	GND	G	1
E5	TxIN16	1	1
E6	VCC	Р	1
E7	TxIN24	1	1
E8	GND	G	1
F1	TxIN5	1	1
F2	NC		1
F3	NC		1
F4	TxIN12	1	1
F5	TxIN17	1	1
F6	NC		1
F7	TxIN22	1	1
F8	TxIN25	I	1
G1	GND	G	1
G2	TxIN8	1	1
G3	TxIN10	1	1
G4	TxIN13	1	1
G5	R_FB	I	]
G6	GND	G	1
G7	TxIN21	I	1
G8	TxIN23	1	1
H1	TxIN9	I	1
H2	VCC	Р	1
H3	TxIN11	I	]
H4	TxIN14	I	]
H5	TxIN15	I	]
H6	TxIN18	I	]
H7	TxIN19	I	]
H8	TxIN20	I	
	•		

	By Pin Type	
G4	TxIN13	
H4	TxIN14	
H5	TxIN15	
E5	TxIN16	
F5	TxIN17	
H6	TxIN18	
H7	TxIN19	
H8	TxIN20	
G7	TxIN21	
F7	TxIN22	
G8	TxIN23	
E7	TxIN24	I
F8	TxIN25	I
D8	TxIN26	I
A1	TxIN27	I
A6	TxCLKOUT-	0
A7	TxCLKOUT+	0
A2	TxOUT0-	0
A3	TxOUT0+	0
C4	TxOUT1-	0
D4	TxOUT1+	0
B5	TxOUT2-	0
C5	TxOUT2+	0
B6	TxOUT3-	0
A8	TxOUT3+	0
A4	LVDS VCC	Р
A5	LVDS VCC	Р
C7	PLL VCC	Р
E1	VCC	Р
E6	VCC	Р
H2	VCC	Р
B8	NC	
C2	NC	
C3	NC	
F2	NC	
F3	NC	
F6	NC	

G : Ground

I : Input O : Output

P : Power

NC : No Connect

## DS90C365 Pin Description — FPD Link Transmitter

Pin Name	I/O	No.	Description	
TxIN	1	21	TTL level input. This includes: 6 Red, 6 Green, 6 Blue, and 3 control lines—FPLINE,	
			FPFRAME and DRDY (also referred to as HSYNC, VSYNC, Data Enable).	
TxOUT+	0	3	Positive LVDS differential data output.	
TxOUT-	0	3	Negative LVDS differential data output.	
TxCLKIN	1	1	TTL level clock input. Pin name TxCLK IN.	
R_FB	1	1	Programmable strobe select (See Table 1).	
TxCLK OUT+	0	1	Positive LVDS differential clock output.	
TxCLK OUT-	0	1	Negative LVDS differential clock output.	
PWR DOWN	1	1	TTL level input. Assertion (low input) TRI-STATES the outputs, ensuring low current at power	
			down. See Applications Information section.	
V <sub>cc</sub>	1	3	Power supply pins for TTL inputs.	
GND	1	4	Ground pins for TTL inputs.	
PLL V <sub>CC</sub>	1	1	Power supply pin for PLL.	
PLL GND		2	Ground pins for PLL.	
LVDS V <sub>CC</sub>	1	1	Power supply pin for LVDS outputs.	
LVDS GND	1	3	Ground pins for LVDS outputs.	

### **Applications Information**

The DS90C385/DS90C365 are backward compatible with the DS90C383/DS90C363, DS90C383A/DS90C363A and the TSSOP versions are a pin-for-pin replacements. The device (DS90C385/DS90C365) utilizes a different PLL architecture employing an internal 7X clock for enhanced pulse position control.

This device (DS90C385/DS90C365) also features reduced variation of the TCCD parameter which is important for dual pixel applications. (See AN-1084) TCCD variation has been measured to be less than 500ps at 85MHz under normal operating conditions.

This device may also be used as a replacement for the DS90CF583/563 (5V, 65MHz) and DS90CF581/561 (5V, 40MHz) FPD-Link Transmitters with certain considerations/ modifications:

- 1. Change 5V power supply to 3.3V. Provide this supply to the V\_{CC}, LVDS V\_{CC} and PLL V\_{CC} of the transmitter.
- The DS90C385/DS90C365 transmitter input and control inputs accept 3.3V LVTTL/LVCMOS levels. They are not 5V tolerant.
- To implement a falling edge device for the DS90C385/ DS90C365, the R\_FB pin may be tied to ground OR left unconnected (an internal pull-down resistor biases this pin low). Biasing this pin to Vcc implements a rising edge device.

#### TRANSMITTER CLOCK JITTER CYCLE-TO-CYCLE

Figures 15 and 16 illustrate the timing of the input clock relative to the input data. The input clock (TxCLKin) is intentionally shifted to the left –3ns and +3ns to the right when data (Txin0-27) is high. This 3ns of cycle-to-cycle clock jitter is repeated at a period of 2 $\mu$ s, which is the period of the input data (1 $\mu$ s high, 1 $\mu$ s low). At different operating frequencies the N Cycle is changed to maintain the desired 3ns cycle-to-cycle jitter at 2 $\mu$ s period.

#### TRANSMITTER INPUT PINS

The TxIN and control input pins are compatible with LVC-MOS and LVTTL levels. These pins are not 5V tolerant.

#### TRANSMITTER INPUT CLOCK

The transmitter input clock must always be present when the device is enabled ( $\overrightarrow{PWR}$  DOWN = HIGH). If the clock is stopped, the  $\overrightarrow{PWR}$  DOWN pin must be used to disable the PLL. The  $\overrightarrow{PWR}$  DOWN pin must be held low until after the input clock signal has been reapplied. This will ensure a proper device reset and PLL lock to occur.

#### POWER SEQUENCING AND POWERDOWN MODE

Outputs of the transmitter remain in TRI-STATE until the power supply reaches 2V. Clock and data outputs will begin to toggle 10 ms after  $V_{\rm CC}$  has reached 3V and the Power-down pin is above 1.5V. Either device may be placed into a powerdown mode at any time by asserting the Powerdown pin (active low). Total power dissipation for each device will decrease to 5  $\mu$ W (typical).

The transmitter input clock may be applied prior to powering up and enabling the transmitter. The transmitter input clock may also be applied after power up; however, the use of the PWR DOWN pin is required as described in the Transmitter Input Clock section. Do not power up and enable ( $\overline{PWR}$ DOWN = HIGH) the transmitter without a valid clock signal applied to the TxCLK IN pin.

The FPD Link chipset is designed to protect itself from accidental loss of power to either the transmitter or receiver. If power to the transmit board is lost, the receiver clocks (input and output) stop. The data outputs (RxOUT) retain the states they were in when the clocks stopped. When the receiver board loses power, the receiver inputs are controlled by a failsafe bias circuitry. The LVDS inputs are High-Z during initial power on and power off conditions. Current is limited (5 mA per input) by the fixed current mode drivers, thus avoiding the potential for latchup when powering the device.

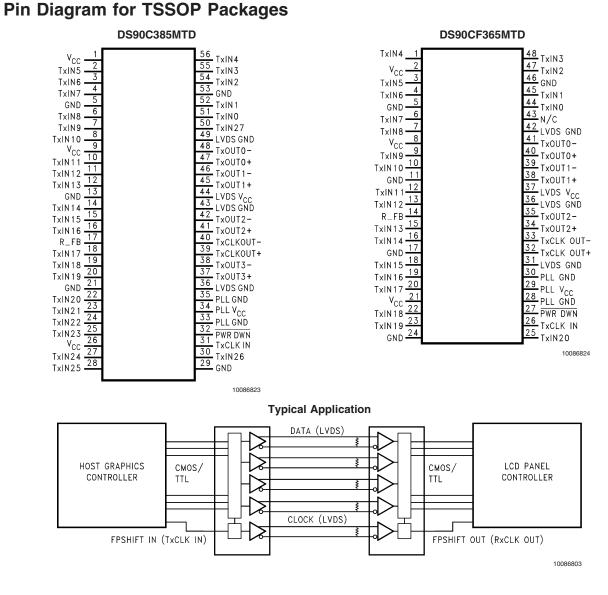
#### **RECEIVER FAILSAFE FEATURE**

The FPD Link receivers have input failsafe bias circuitry to guarantee a stable receiver output for floating or terminated receiver inputs. Under these conditions receiver inputs will be pulled to a HIGH state. This is the case if not all data channels are required in the application. Leave the extra

#### Applications Information (Continued)

channel's inputs open. This minimizes power dissipation and locks the unused channels outputs into a stable known (HIGH) state.

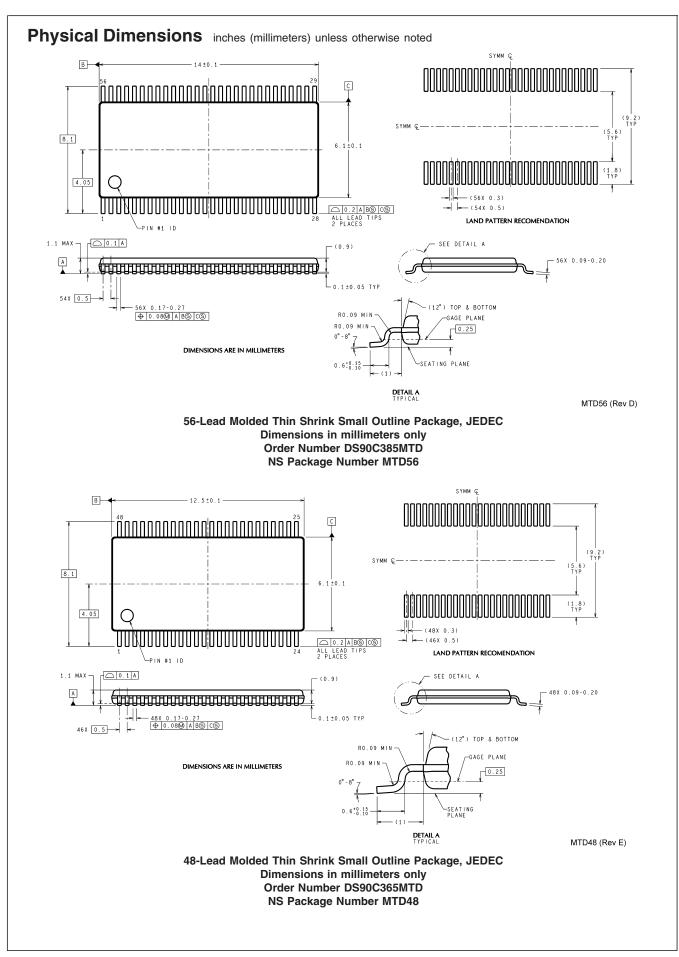
If a clock signal is present, data outputs will all be HIGH; if the clock input is also floating/terminated, data outputs will remain in the last valid state. A floating/terminated clock input will result in a LOW clock output.

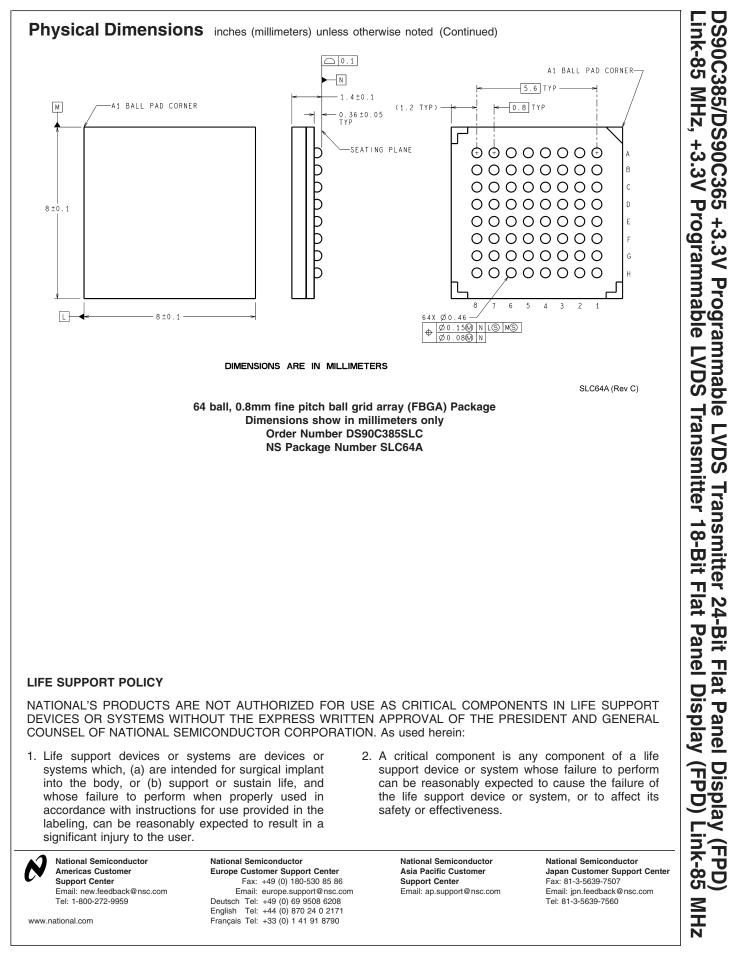




Pin	Condition	Strobe Status
R_FB	$R_FB = V_{CC}$	Rising edge strobe
R_FB	R_FB = GND or NC	Falling edge strobe







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